

July 1992

DS1631/DS3631/DS1632/DS3632/DS1633/DS3633/ DS1634/DS3634 CMOS Dual Peripheral Drivers

General Description

The DS1631 series of dual peripheral drivers was designed to be a universal set of interface components for CMOS circuits.

Each circuit has CMOS compatible inputs with thresholds that track as a function of V_{CC} (approximately 1/2 V_{CC}). The inputs are PNPs providing the high impedance necessary for interfacing with CMOS.

Outputs have high voltage capability, minimum breakdown voltage is 56V at 250 μA.

The outputs are Darlington connected transistors. This allows high current operation (300 mA max) at low internal V_{CC} current levels since base drive for the output transistor is obtained from the load in proportion to the required loading conditions. This is essential in order to minimize loading on the CMOS logic supply.

Typical $V_{CC} = 5V$ power is 28 mW with both outputs ON. V_{CC} operating range is 4.5V to 15V.

The circuit also features output transistor protection if the V_{CC} supply is lost by forcing the output into the high impedance OFF state with the same breakdown levels as when V_{CC} was applied.

Pin-outs are the same as the respective logic functions found in the following popular series of circuits: DS75451, DS75461. This feature allows direct conversion of present systems to the MM74C CMOS family and DS1631 series circuits with great power savings.

The DS1631 series is also TTL compatible at $V_{CC} = 5V$.

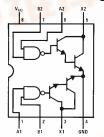
Features

- CMOS compatible inputs
- High impedance inputs
- 56V min ■ High output voltage breakdown
- High output current capability
- 300 mA max

PNP's

- Same pin-outs and logic functions as DS75451 and DS75461 series circuits
- Low V_{CC} power dissipation (28 mW both outputs "ON"

Connection Diagrams (Dual-In-Line and Metal Can Packages)



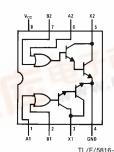
Order Number DS1631J-8 or DS3631N



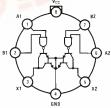
Order Number DS1632J-8 or DS3632N



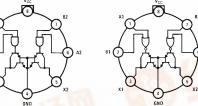
TL/F/5816-3 Top View Order Number DS1633J-8 or DS3633N



Top View Order Number DS1634J-8 or DS3634N



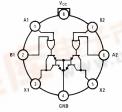
Top View Top View (Pin 4 is electrically connected to the (Pin 4 is electrically connected to the



See NS Package Number J08A or N08E

TI /F/5816-6 TI /F/5816-7

Top View (Pin 4 is electrically connected to the



Top View

(Pin 4 is electrically connected to the case.)

Order Number DS1634H

case.) Order Number DS1631H

Order Number DS1632H

Order Number DS1633H See NS Package Number H08C

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Absolute Maximum Ra If Military/Aerospace specified of please contact the National office/Distributors for availability	devices are required, Semiconductor Sales
Supply Voltage	16V
Voltage at Inputs	$-$ 0.3V to V $_{\rm CC}$ $+$ 0.3V
Output Voltage	56V
Storage Temperature Range	-65°C to +150°C
Maximum Power Dissipation* at 25°	C
Cavity Package	1133 mW
Molded Package	1022 mW
TO-5 Package	787 mW
Lead Temperature (Soldering, 4 sec.	. 260°C
*Derate cavity package 7.6 mW/°C above 2 8.2 mW/°C above 25°C; derate TO-5 package	

Operating Conditions							
	Min	Max	Units				
Supply Voltage, V_{CC}							
DS1631/DS1632/	4.5	15	V				
DS1633/DS1634							
DS3631/DS3632/	4.75	15	V				
DS3633/DS3634							
Temperature, T _A							
DS1631/DS1632/	-55	+ 125	°C				
DS1633/DS1634							
DS3631/DS3632/	0	+70	°C				
DS3633/DS3634							

Electrical Characteristics (Notes 2 and 3)

Symbol	Parameter	Conditions			Min	Тур	Max	Units
ALL CIR	CUITS							
V _{IH}	Logical "1" Input Voltage	(Figure 1) $V_{CC} = 5V$			3.5	2.5		V
			V _{CC} = 10V		8.0	5		٧
			V _{CC} = 15V			7.5		V
V _{IL}	Logical "0" Input Voltage	(Figure 1)	$V_{CC} = 5V$			2.5	1.5	٧
			V _{CC} = 10V			5.5	2.0	٧
			V _{CC} = 15V			7.5	2.5	٧
I _{IH}	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15\	•			0.1	10	μΑ
I _{IL}	Logical "0" Input Current	Current $V_{IN} = 0.4V$, (Figure 3) $V_{CC} = 5V$				-50	-120	μΑ
			V _{CC} = 15V			-200	-360	μΑ
V _{OH}	Output Breakdown Voltage	$V_{CC} = 15V, I_{OH} = 250$	μA, (Figure 1)		56	65		٧
V _{OL}	Output Low Voltage	V _{CC} = Min, (Figure 1),						
		DS1631, DS1632,	I _{OL} = 100 mA			0.85	1.1	V
		DS1633, DS1634	I _{OL} = 300 mA			1.1	1.4	V
		V _{CC} = Min, (<i>Figure 1</i>), DS3631, DS3632, DS3633, DS3634	400 4			0.05	4.0	\ ,,
			I _{OL} = 100 mA			0.85	1.0	V
D04004	/D00004		I _{OL} = 300 mA			1.1	1.3	V
DS1631/	1)/ (Firms 4)	\	0.441		-		A
ICC(0)	Supply Currents	$V_{IN} = 0V$, (Figure 4)	V _{CC} = 5V	Output Low		7	11	mA
		(Firmer 1)	V _{CC} = 15V	Both Drivers		14	20	mA
I _{CC(1)}		(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output High		2	3	mA
	D	V 5V T 0500	$V_{CC} = 15V, V_{IN} = 15V$			7.5	10	mA
t _{PD1}	Propagation to "1"	$V_{CC} = 5V$, $T_A = 25$ °C, $C_L = 15$ pF, $R_L = 50\Omega$, $V_L = 10V$, (Figure 5)				500		ns
t _{PD0}	Propagation to "0"	$V_{CC}=5V, T_A=25^{\circ}C, C_L=15 pF, R_L=50\Omega, V_L=10V, \ (Figure 5)$				750		ns
DS1632	/DS3632							
I _{CC(0)}	Supply Currents	(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output Low		8	12	mA
(.,			$V_{CC} = 15V, V_{IN} = 15V$			18	23	mA
I _{CC(1)}	V _{IN} =	V _{IN} = 0V, (Figure 4)	$V_{CC} = 5V$	Output High		2.5	3.5	mA
			$V_{CC} = 15V$			9	14	mA
t _{PD1}	Propagation to "1"	$V_{CC}=5V, T_A=25^{\circ}C, C_L=15 pF, R_L=50\Omega, V_L=10V, \ (Figure 5)$				500		ns
t _{PD0}	Propagation to "0"	$V_{CC} = 5V, T_A = 25^{\circ}C, C_L = 15 \text{ pF}, R_L = 50\Omega, V_L = 10V, $ (Figure 5)				750		ns

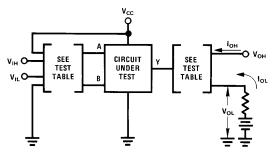
Symbol	Parameter	Conditions			Min	Тур	Max	Units
DS1633/	DS3633							
I _{CC(0)}	Supply Currents	V _{IN} = 0V, (Figure 4)	$V_{CC} = 5V$	Output Low		7.5	12	mA
			$V_{CC} = 15V$			16	23	mA
I _{CC(1)}		(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output High		2	4	mA
			$V_{CC} = 15V, V_{IN} = 15V$			7.2	15	mA
t _{PD1}	Propagation to "1"	$V_{CC}=5V, T_A=25^{\circ}C, C_L=15~pF, R_L=50\Omega, V_L=10V, \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$				500		ns
t _{PD0}	Propagation to "0"	$V_{CC}=5V, T_{A}=25^{\circ}C, C_{L}=15$ pF, $R_{L}=50\Omega, V_{L}=10V,$ (Figure 5)				750		ns
DS1634/	DS3634							
I _{CC(0)}	Supply Currents	(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output Low		7.5	12	mA
			$V_{CC} = 15V, V_{IN} = 15V$			18	23	mA
I _{CC(1)}		V _{IN} = 0V, (Figure 4)	$V_{CC} = 5V$	Output High		3	5	mA
			$V_{CC} = 15V$			11	18	mA
t _{PD1}	Propagation to "1"	$V_{CC}=5V, T_{A}=25^{\circ}C, C_{L}=15~pF, R_{L}=50\Omega, V_{L}=10V, \ (Figure~5)$				500		ns
t _{PD0}	Propagation to "0"	$V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 15$ pF, $R_L = 50\Omega$, $V_L = 10V$, (Figure 5)				750		ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Unless otherwise specified min/max limits apply across the -55°C to +125°C temperature range for the DS1631, DS1632, DS1633 and DS1634 and across the 0°C to +70°C range for the DS3631, DS3632, DS3633 and DS3634. All typical values are for T_A = 25°C.

Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as may or min on shedulate value basis

Test Circuits



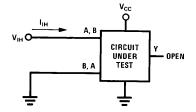
TL/F/5816-9

	Input	O45	Output				
Circuit	Under Test	Other Input	Apply	Measure			
DS3631	V _{IH}	V _{IH}	I _{OH}	V _{OH}			
	V _{IL}	V _{CC}	I _{OL}	V _{OL}			
DS3632	V _{IH}	V _{IH}	I _{OL}	V _{OL}			
	V _{IL}	V _{CC}	I _{OH}	V _{OH}			
DS3633	V _{IH}	GND	I _{OH}	V _{OH}			
	V _{IL}	V _{IL}	I _{OL}	V _{OL}			
DS3634	V _{IH}	GND	I _{OL}	V _{OL}			
	V _{IL}	V _{IL}	I _{OH}	V _{OH}			

Note: Each input is tested separately.

FIGURE 1. V_{IH} , V_{IL} , V_{OH} , V_{OL}

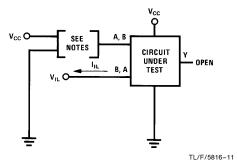
Test Circuits (Continued)



TL/F/5816-10

Each input is tested separately.

FIGURE 2. I_{IH}



V₁ OPEN

ICCH | ICCL | X

A

B

GND

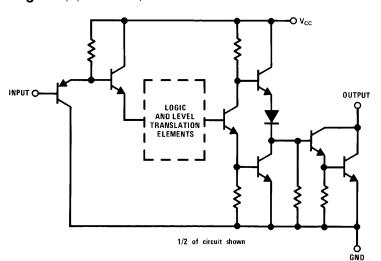
TL/F/5816-12
Both gates are tested simultaneously.
FIGURE 4. I_{CC} for AND and NAND Circuits

Note A: Each input is tested separately.

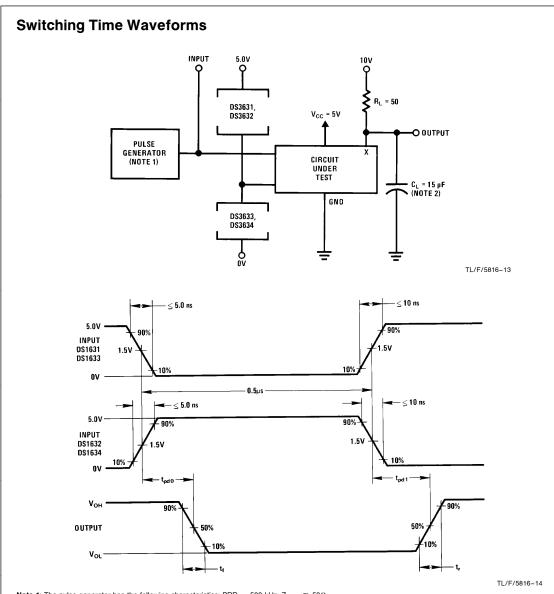
Note B: When testing DS1633 and DS1634 input not under test is grounded. For all other circuits it is at $V_{\rm CC}$.

FIGURE 3. $I_{\rm IL}$

Schematic Diagram (Equivalent Circuit)



TL/F/5816-15

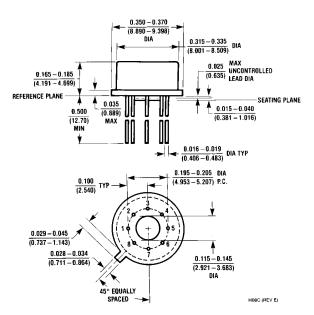


Note 1: The pulse generator has the following characteristics: PRR = 500 kHz, $\rm Z_{OUT} \approx 50\Omega$

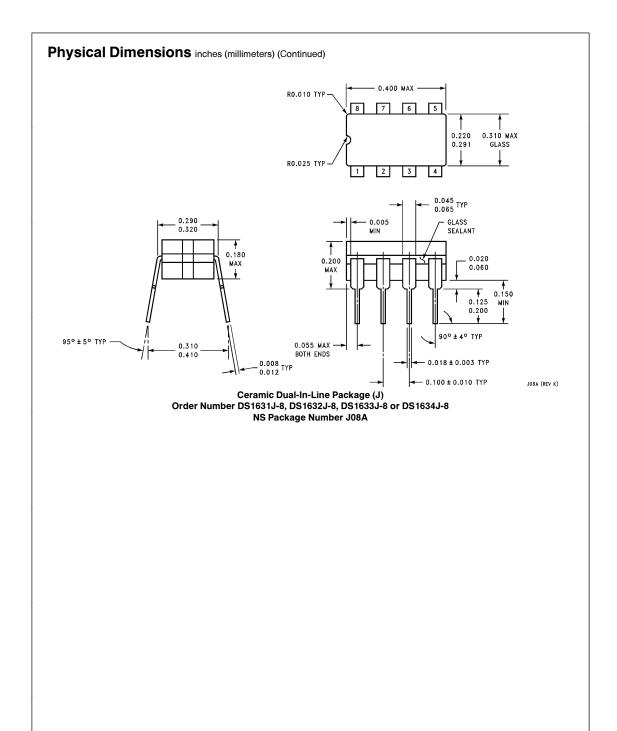
Note 2: C_L includes probe and jig capacitance

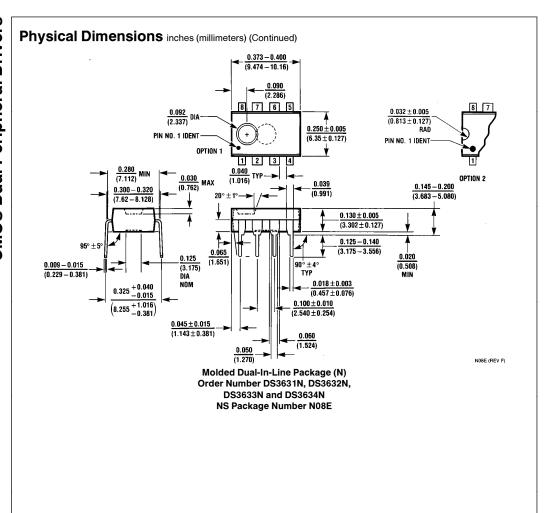
FIGURE 5. Switching Times

Physical Dimensions inches (millimeters)



Metal Can Package (H) Order Number DS1631H, DS1632H, DS1633H or DS1634H NS Package Number H08C





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